TOSHIBA Intelligent Power Module Silicon N Channel IGBT

MIG200J201H

High Power Switching Applications Motor Control Applications

• Integrates inverter, brake power circuits & control circuits (IGBT drive units, protection units for over-current, under-voltage & over-temperature) in one package.

The electrodes are isolated from case.

High speed type IGBT: $V_{CE (sat)} = 2.5V (max)$

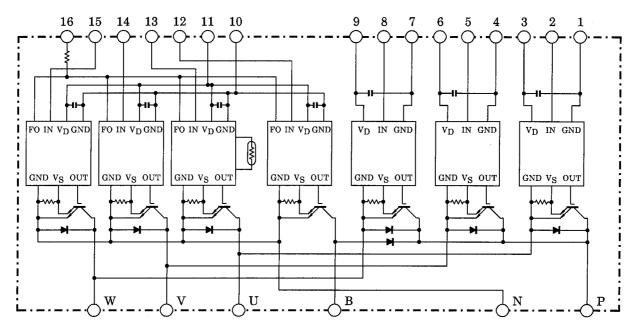
 $t_{off} = 2.0 \mu s \text{ (max)}$

 $t_{rr} = 0.15\mu s \text{ (max)}$

Package dimensions : TOSHIBA 2-136A1A

Weight:

Equivalent Circuit



2. IN (U) 1. GND (U) 3. $V_D(U)$ 4. GND (V) 5. IN (V) 6. $V_D(V)$ 9. V_D (W) 15.IN (Z) 7. GND (W) 8. IN (W) 10.GND (L) 11.V_D (L) 12.IN (B)

13.IN (X) 14.IN (Y) 16.FO

> 1 2003-08-07

Maximum Ratings ($T_j = 25$ °C)

Stage	Characteristic	Condition	Symbol	Ratings	Unit
Inverter	Supply voltage	P-N power terminal	V _{CC}	450	V
	Collector-emitter voltage	_	V _{CES}	600	V
	Collector current	Tc = 25°C, DC	Ic	200	Α
ilivertei	Forward current	Tc = 25°C, DC	lF	200	Α
	Collector power dissipation	Tc = 25°C	PC	800	W
	Junction temperature	_	Tj	150	°C
Brake	Supply voltage	P-N power terminal	V _{CC}	450	V
	Collector-emitter voltage	_	V _{CES}	600	V
	Collector current	Tc = 25°C, DC	IC	100	Α
	Reverse voltage	_	V _R	600	V
	Forward current	Tc = 25°C, DC	lF	100	Α
	Collector power dissipation	Tc = 25°C	PC	400	W
	Junction temperature	_	Tj	150	°C
Control	Control supply voltage	VD-GND terminal	V _D	20	V
	Input voltage	IN-GND terminal	V _{IN}	20	V
	Fault output voltage	FO-GND (L) terminal	V _{FO}	20	V
	Fault output current	FO sink current	I _{FO}	14	mA
Module	Operating temperature	_	T _C	-20~+100	°C
	Storage temperature range	_	T _{stg}	-40~+125	°C
	Isolation voltage	AC 1 minute	V _{ISO}	2500	V
	Screw torque	M5		3	N·m

Electrical Characteristics ($T_j = 25$ °C)

a. Inverter stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Collector cut-off current	ICEX	V _{CE} = 600V	T _j = 25°C	_	_	1	mA
Collector cut-on current			T _j = 125°C	_	_	10	IIIA
Callantar are itter activistics valtare		V_D = 15V, I_C = 200A V_{IN} = 3V \rightarrow 0V	T _j = 25°C	_	2.0	2.5	V
Collector-emitter saturation voltage			T _j = 125°C	_	2.0	_	V
Forward voltage	V _F	I _F = 200A		_	2.1	2.7	V
	t _{on}			8.0	1.5	2.2	
	t _{c (on)}	V_{CC} = 300V, I_{C} = 200A V_{D} = 15V, V_{IN} = 3V \leftrightarrow 0V Inductive load (Note 1)		_	0.5	1.0	
Switching time	t _{rr}			_	0.08	0.15	μs
	t _{off}			_	1.2	2.0	
	t _{c (off)}			_	0.3	0.6	



b. Brake stage

Characteristic	Symbol	Test Condition		Min	Тур.	Max	Unit
Cellector cut-off current	ICEX	V _{CE} = 600V	T _j = 25°C	_	_	1	mA
Cellector cut-on current			T _j = 125°C	_	_	10	IIIA
Collector-emitter saturation voltage	V _{CE} (sat)	$V_D = 15V, I_C = 100A$ $V_{IN} = 3V \rightarrow 0V$	T _j = 25°C	1	2.0	2.5	V
			T _j = 125°C	I	2.0	1	V
Reverse current	I _R	V _R = 600V	T _j = 25°C	I	_	1	- mA
Neverse current			T _j = 125°C	I	_	10	
Forward voltage	V _F	I _F = 100A			2.1	3.0	V
	t _{on}	V_{CC} = 300V, I_C = 100A V_D = 15V, V_{IN} = 3V \leftrightarrow 0V Inductive load (Note 1)		0.8	1.5	2.2	
	t _{c (on)}			I	0.5	1.0	
Switching time	t _{rr}			_	0.30	0.50	μs
	t _{off}			_	1.2	2.0	
	t _{c (off)}			_	0.3	0.6	

c. Control stage $(T_j = 25^{\circ}C)$

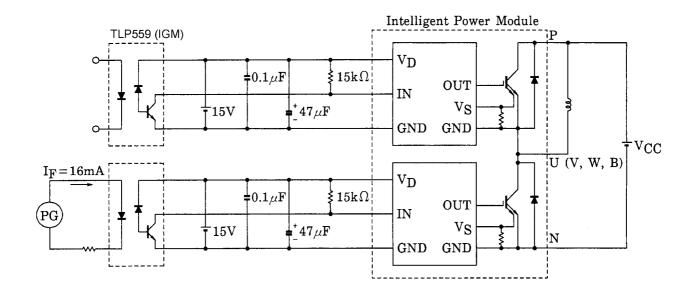
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Control circuit current	High side	I _{D (H)}	- V _D = 15V	_	20	30	mA
	Low side	I _{D (L)}		_	80	120	
Input on signal voltage		V _{IN (on)}	V _D = 15V, I _C = 200mA	0.9	1.1	1.3	V
Fault output current	Protection	I _{FO (on)}	151	8	10	12	mA
	Normal	I _{FO (off)}	- V _D = 15V	_	_	1	
Over current protection trip level	Inverter	00	V _D = 15V, Tj = 125°C	320	400	_	A
	Brake	- oc		210	300	_	
Short circuit protection trip level	Inverter	00	V _D = 15V, T _j = 125°C	480	600	_	Α
	Brake	SC		315	450	_	
Over current cut-off time		t _{off (OC)}	V _D = 15V	_	10	_	μs
Over	Trip level	ОТ	Case temperature	111	118	125	°C
temperature protection	Reset leevel	OTr		93	100	107	C
Control supply under voltage protection	Trip level	UV		11.3	12.0	12.7	V
	Reset leevel	UVr	_	11.8	12.5	13.2	V
Fault output pulse width		t _{FO}	V _D = 15V	1	2	3	ms

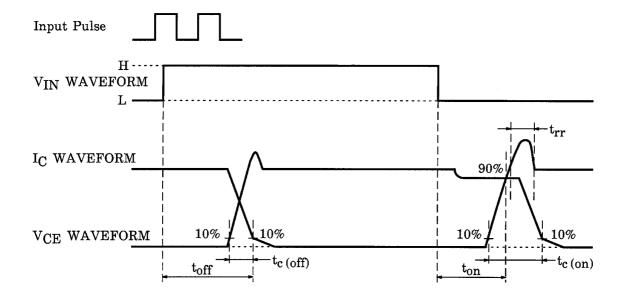
3 2003-08-07

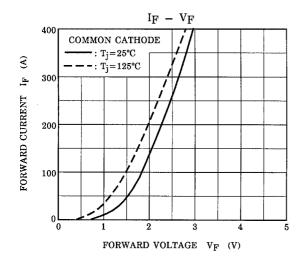
d. Thermal resistance $(T_j = 25^{\circ}C)$

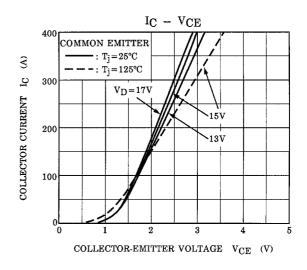
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Rth (j-c)	Inverter IGBT	_	_	0.156	°C / W
Junction to case thermal resistance		Inverter FRD	_	_	0.416	
Junction to case thermal resistance		Brake IGBT	_	_	0.312	
		Brake FRD	_	_	1.00	
Case to fin thermal resistance	Rth (c-f)	Compound is applied	_	0.04	_	°C/W

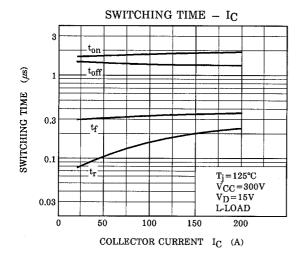
Note 1: Switching time test circuit & timing char

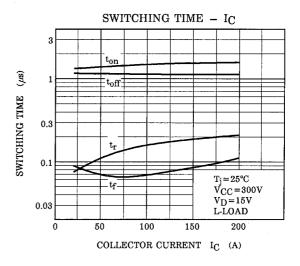


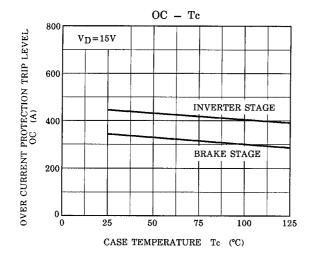


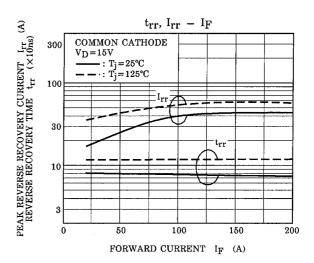


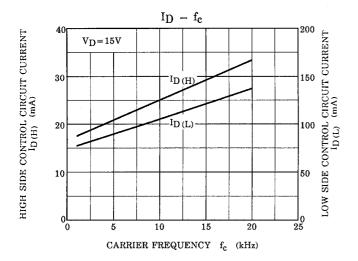


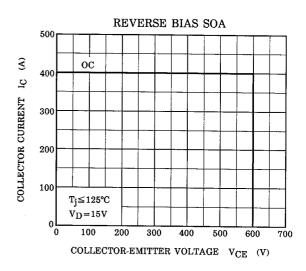


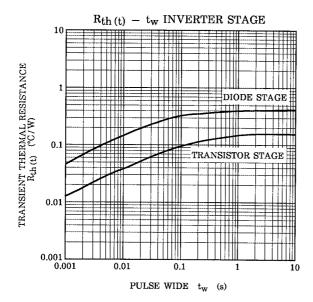


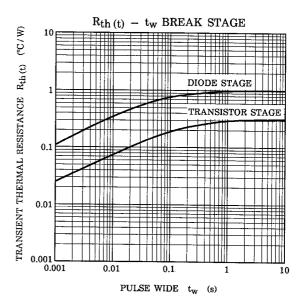








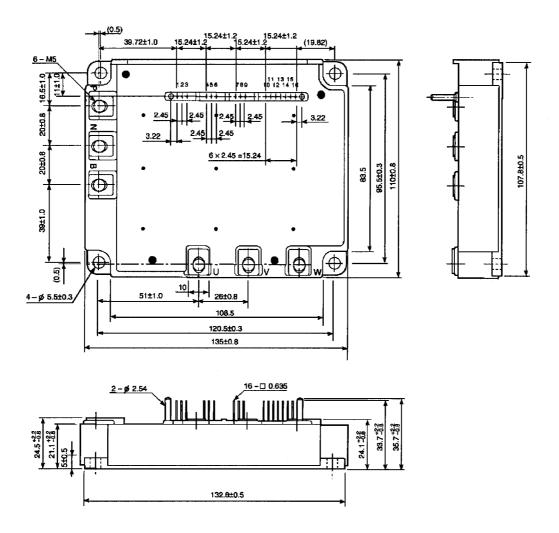




6 2003-08-07

Package Dimensions: TOSHIBA 2-136A1A

Unit: mm



RESTRICTIONS ON PRODUCT USE

030619EAA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.